



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DS}	Drain to Source Voltage		25	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current -Continuous (Package Limited)		35	
I _D	-Continuous (Die Limited)		60	А
	-Pulsed	(Note 1)	224	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	73	mJ
P _D	Power Dissipation		50	W
T _J , T _{STG}	Operating and Storage Temperature		-55 to 175	°C
Therma	Characteristics			
$R_{\theta JC}$	Thermal Resistance, Junction to Case TO-252, TO-251		3.0	°C/W
P	There all Deviators and Investigated Applicant TO 050 TO 054		100	0000

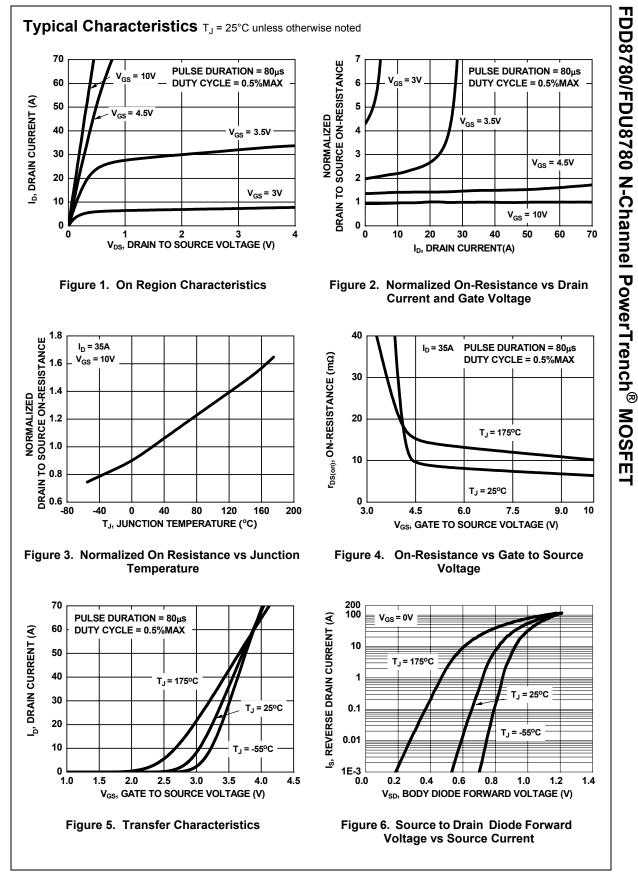
$R_{\theta JC}$	Thermal Resistance, Junction to Case TO-252, TO-251	3.0	°C/VV
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient TO-252, TO-251	100	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient TO-252,1in ² copper pad area	52	°C/W

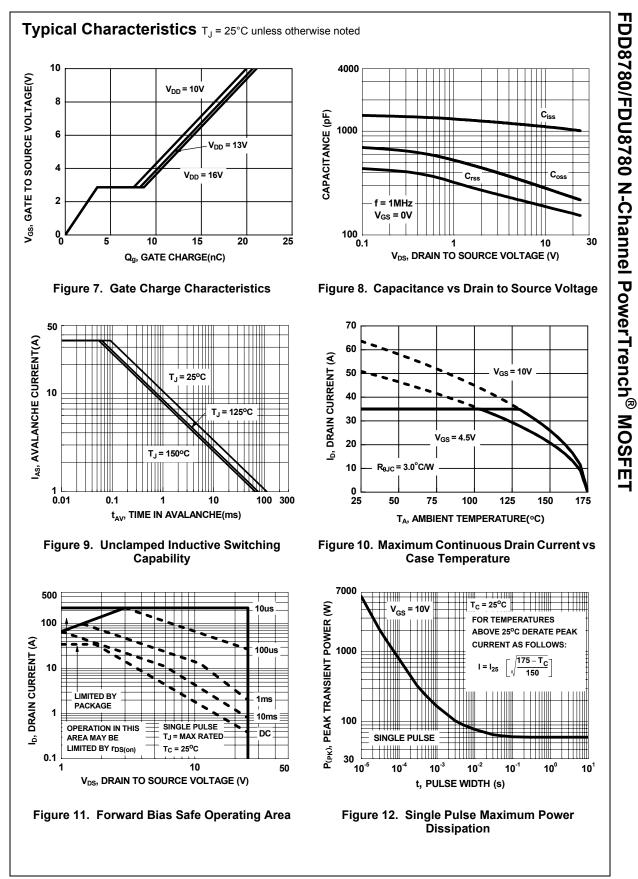
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8780	FDD8780	TO-252AA	13"	12mm	2500 units
FDU8780	FDU8780	TO-251AA	N/A(Tube)	N/A	75 units
FDU8780	FDU8780_F071	TO-251AA	N/A(Tube)	N/A	75 units

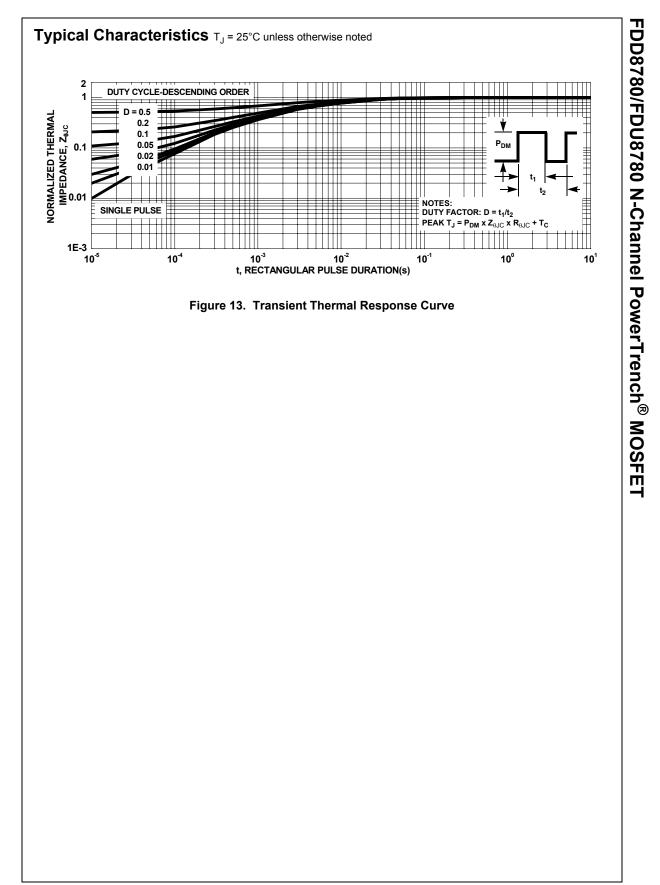
FDD8780/FDU8780 N-Channel PowerTrench[®] MOSFET

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units	
Off Chara	cteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V	25			V	
ΔB_{VDSS} ΔT_J	Breakdown Voltage Temperature Coefficient	$I_D = 250\mu$ A, referenced to 25°C		12		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 20V,$ $V_{GS} = 0V$ $T_J = 150^{\circ}C$			1 250	μA	
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V			±100	nA	
On Chara	cteristics			1	1	1	
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \mu A$	1.2	1.8	2.5	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\mu A$, referenced to $25^{\circ}C$		-6.3		mV/°C	
		V _{GS} = 10V, I _D = 35A		6.5	8.5		
r.	Drain to Source On Resistance	V _{GS} = 4.5V, I _D = 35A		9.1	12.0	mΩ	
r _{DS(on)}		V _{GS} = 10V, I _D = 35A T _J = 175°C		10.4	15.0	- 1115.2	
•	Characteristics			T	1	1	
C _{iss}	Input Capacitance	V _{DS} = 13V, V _{GS} = 0V,		1080	1440	pF	
C _{oss}	Output Capacitance	f = 1MHz		265	355	pF	
C _{rss}	Reverse Transfer Capacitance			180	270	pF	
R _g	Gate Resistance	f = 1MHz		0.9		Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			7	14	ns	
t _r	Rise Time	V _{DD} = 13V, I _D = 35A -V _{GS} = 10V, R _{GS} = 17Ω		9	18	ns	
t _{d(off)}	Turn-Off Delay Time			43	69	ns	
t _f	Fall Time			24	38	ns	
Qg	Total Gate Charge	$V_{GS} = 0V \text{ to } 10V$		21	29	nC	
Qg	Total Gate Charge	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$		11.2	16	nC	
Q _{gs}	Gate to Source Gate Charge	$I_a = 1.0 \text{mA}$		3.5		nC	
Q _{gd}	Gate to Drain "Miller"Charge	9		4.7		nC	
ວrain-Soເ	urce Diode Characteristics						
N/	Source to Drain Diode Forward Voltage	V _{GS} = 0V, I _S = 35A		0.92	1.25	V	
V		V _{GS} = 0V, I _S = 15A		0.84	1.0	V	
V _{SD}				1	1	1	
V _{SD}	Reverse Recovery Time	I _F = 35A, di/dt = 100A/μs		28	42	ns	





FDD8780/FDU8780 Rev. B



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